

MPSA44

Preferred Device

High Voltage Transistor

NPN Silicon



ON Semiconductor®

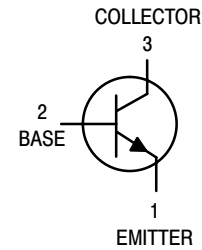
<http://onsemi.com>

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	400	Vdc
Collector–Base Voltage	V_{CBO}	500	Vdc
Emitter–Base Voltage	V_{EBO}	6.0	Vdc
Collector Current – Continuous	I_C	300	mA _{dc}
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625 5.0	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5 12	Watts mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

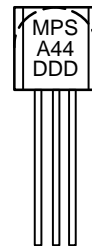
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction–to–Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction–to–Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$



MARKING DIAGRAM



TO-92 (TO-226AA)
CASE 29-11
Style 1



MPSA44= Specific Device Cod
DDD = Date Code

ORDERING INFORMATION

Device	Package	Shipping
MPSA44	TO-92	5000 Units / Bag
MPSA44RLRA	TO-92	2000 / Tape & Reel
MPSA44RL1	TO-92	2000 / Tape & Reel

Preferred devices are recommended choices for future use and best overall value.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Breakdown Voltage (Note 1) (I _C = 1.0 mA _{dc} , I _B = 0)	V _{(BR)CEO}	400	–	V _{dc}
Collector–Emitter Breakdown Voltage (I _C = 100 μA _{dc} , V _{BE} = 0)	V _{(BR)CES}	500	–	V _{dc}
Collector–Base Breakdown Voltage (I _C = 100 μA _{dc} , I _E = 0)	V _{(BR)CBO}	500	–	V _{dc}
Emitter–Base Breakdown Voltage (I _E = 10 μA _{dc} , I _C = 0)	V _{(BR)EBO}	6.0	–	V _{dc}
Collector Cutoff Current (V _{CB} = 400 V _{dc} , I _E = 0)	I _{CBO}	–	0.1	μA _{dc}
Collector Cutoff Current (V _{CE} = 400 V _{dc} , V _{BE} = 0)	I _{CES}	–	500	nA _{dc}
Emitter Cutoff Current (V _{EB} = 4.0 V _{dc} , I _C = 0)	I _{EBO}	–	0.1	μA _{dc}
ON CHARACTERISTICS (Note 1)				
DC Current Gain (Note 1) (I _C = 1.0 mA _{dc} , V _{CE} = 10 V _{dc}) (I _C = 10 mA _{dc} , V _{CE} = 10 V _{dc}) (I _C = 50 mA _{dc} , V _{CE} = 10 V _{dc}) (I _C = 100 mA _{dc} , V _{CE} = 10 V _{dc})	h _{FE}	40 50 45 40	– 200 – –	–
Collector–Emitter Saturation Voltage (Note 1) (I _C = 1.0 mA _{dc} , I _B = 0.1 mA _{dc}) (I _C = 10 mA _{dc} , I _B = 1.0 mA _{dc}) (I _C = 50 mA _{dc} , I _B = 5.0 mA _{dc})	V _{CE(sat)}	– – –	0.4 0.5 0.75	V _{dc}
Base–Emitter Saturation Voltage (I _C = 10 mA _{dc} , I _B = 1.0 mA _{dc})	V _{BE(sat)}	–	0.75	V _{dc}
SMALL–SIGNAL CHARACTERISTICS				
Output Capacitance (V _{CB} = 20 V _{dc} , I _E = 0, f = 1.0 MHz)	C _{obo}	–	7.0	pF
Input Capacitance (V _{EB} = 0.5 V _{dc} , I _C = 0, f = 1.0 MHz)	C _{ibo}	–	130	pF
Small–Signal Current Gain (I _C = 10 mA _{dc} , V _{CE} = 10 V _{dc} , f = 20 MHz)	h _{fe}	1.0	–	–

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

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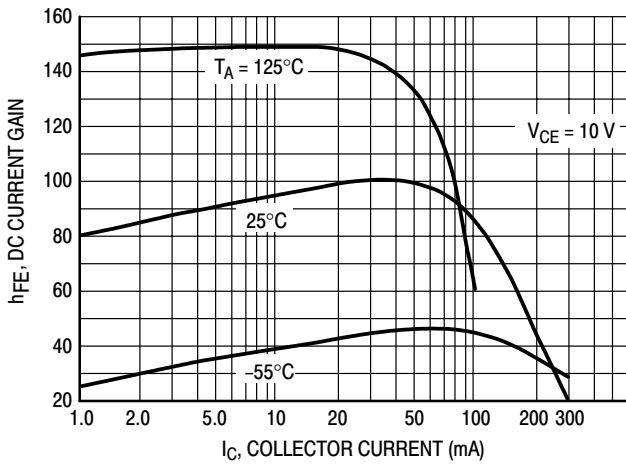


Figure 1. DC Current Gain

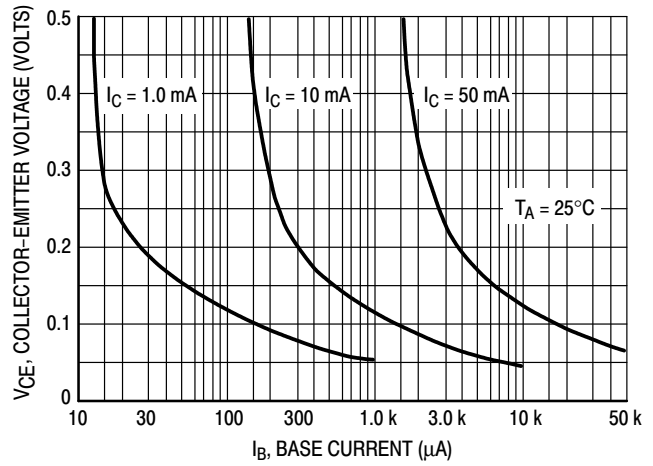


Figure 2. Collector Saturation Region

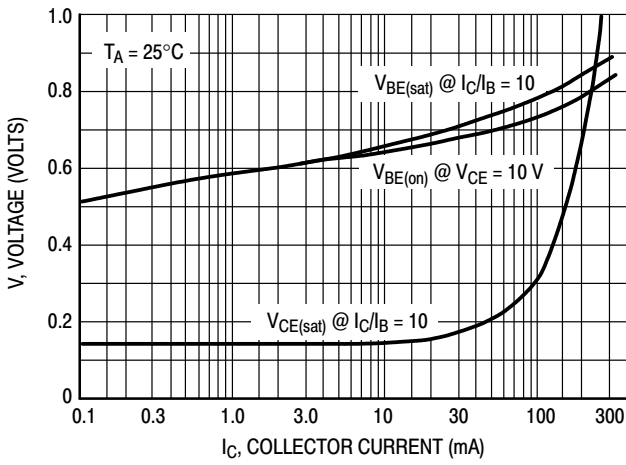


Figure 3. "On" Voltages

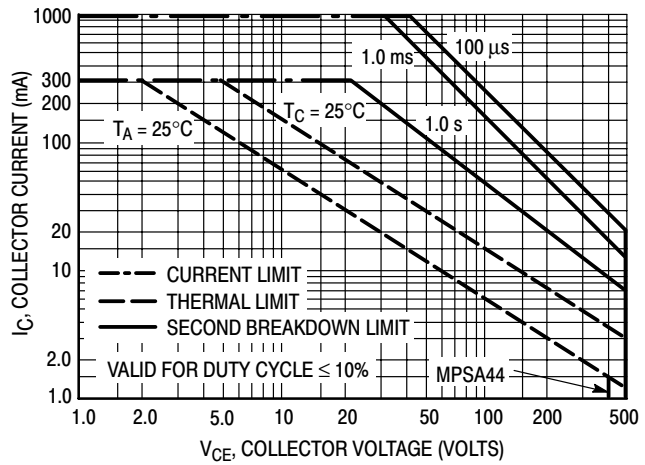


Figure 4. Active Region - Safe Operating Area

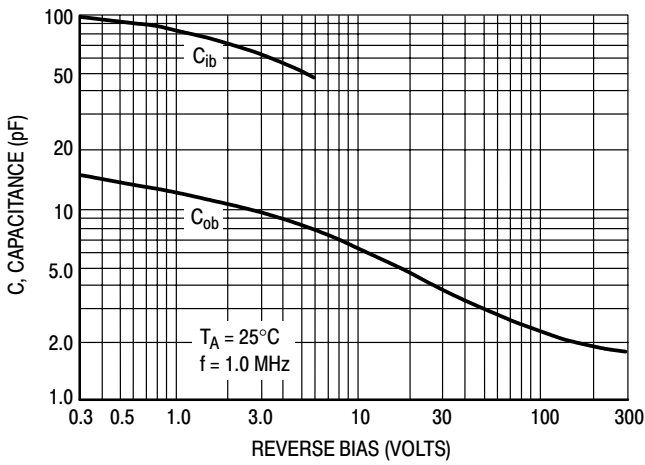


Figure 5. Capacitance

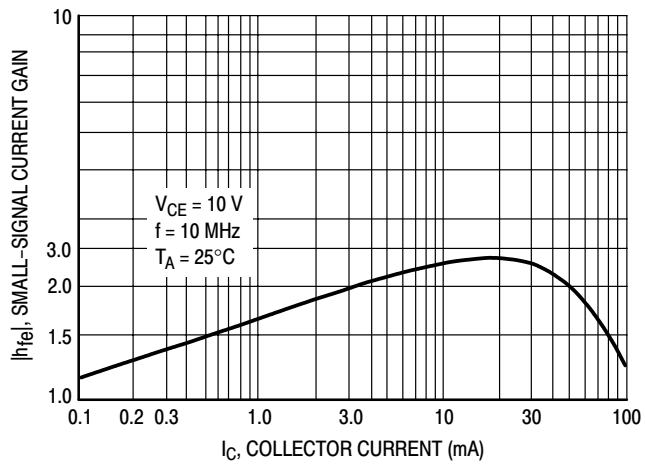


Figure 6. High Frequency Current Gain

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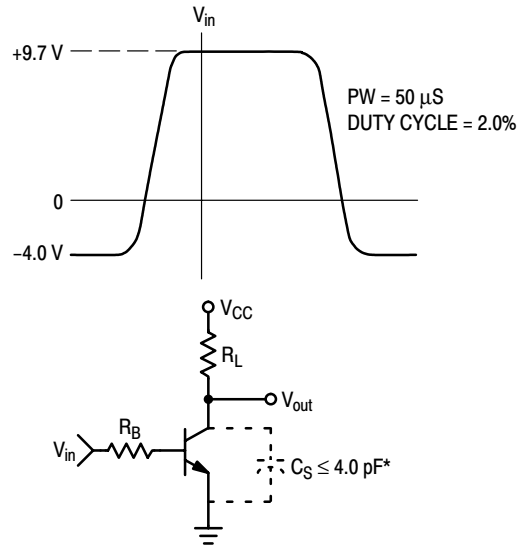
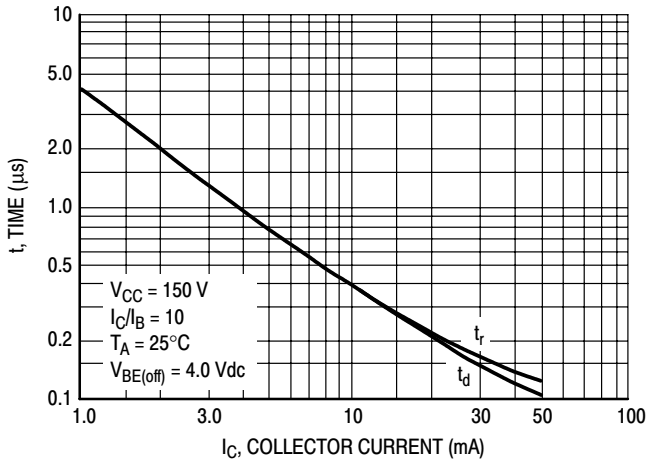


Figure 7. Turn-On Switching Times and Test Circuit

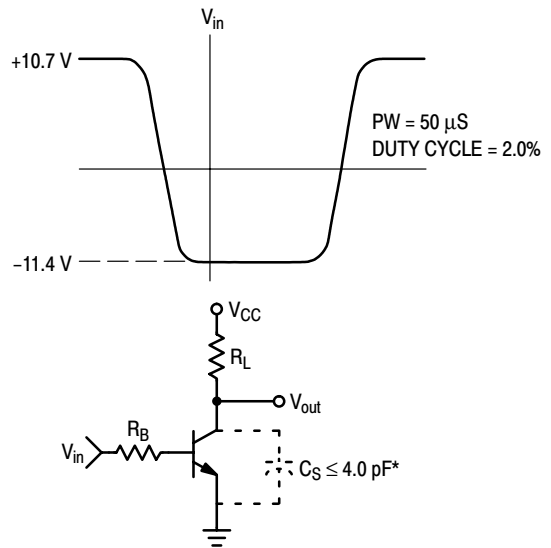
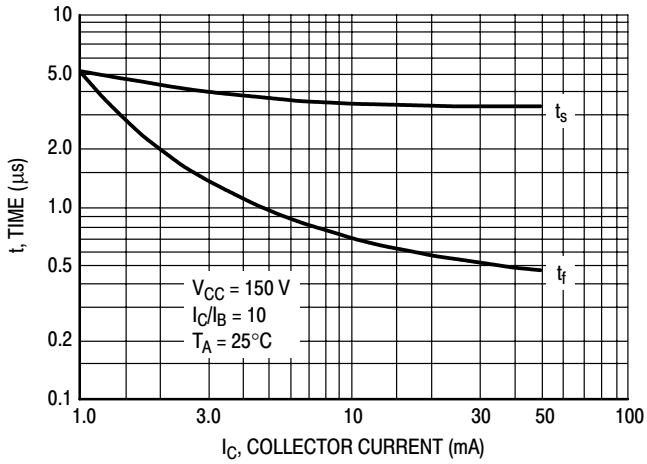


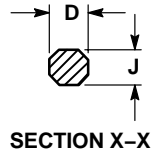
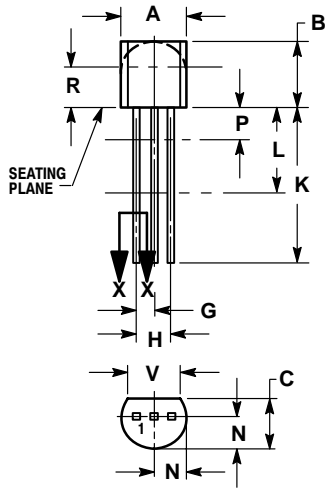
Figure 8. Turn-Off Switching Times and Test Circuit

*Total Shunt Capacitance of Test Jig and Connectors.

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PACKAGE DIMENSIONS

TO-92 (TO-226)
CASE 29-11
ISSUE AL



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

STYLE 1:

1. EMITTER
2. BASE
3. COLLECTOR

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